

40V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BVDSS	RDS(ON) max	Package	I _{D max} $T_A = +25^{\circ}C$	
40)/	$33m\Omega$ @ V _{GS} = -10V	U-DFN2020-6	-6A	
-40V	50mΩ @ V _{GS} = -4.5V	(Type E)	-4.9A	

Description

This new generation MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Load Switching
- Battery Management Application
- Power Management Functions

Features

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low Gate Threshold Voltage
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

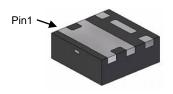
 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

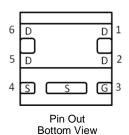
Mechanical Data

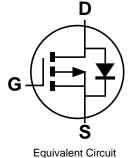
- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.0065 grams (Approximate)

U-DFN2020-6 (Type E)



Bottom View





Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Quantity Per Reel
DMP4047LFDE-7	PE	7	3,000
DMP4047LFDE-13	PE	13	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1:



PE = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2012		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	Z		Н		J	K	L	М	N	0	Р	R
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2:



PE = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020)

W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key												
Year	2012		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	2		0	1	2	3	4	5	6	7	8	9
Week	1-26			27-52				53				
Code	A-Z			A-Z a-z					Z			
Internal Code	Sun	1	Mon		Tue	W	ed	Thu		Fri		Sat
Code	T		U		V	V	٧	Х		Υ		Z



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	-40	V		
Gate-Source Voltage			V _{GSS}	±20	V
Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$			lD	-3.3 -2.6	А
Continuous Drain Current (Note 5) V _{GS} = -10V	$T_A = +25$ °C $T_A = +70$ °C	lo	-5.3 -4.2	А	
Continuous Preis Correct (Note C) V.s. 40V	lo	-6.0 -4.8	А		
Continuous Drain Current (Note 6) Vos = -10V	I _D	-9.5 -7.6	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	IDM	-40	A		
Maximum Body Diode Continuous Current			Is	-3	Α

Thermal Characteristics

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T _A = +25°C	D-	0.7	W	
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	Pb	0.42	VV	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D	180	°C/W	
Thermal Resistance, Junction to Ambient (Note 3)	t<5s	R _θ JA	76	C/VV	
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	D-	2.1	W	
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	PD	1.3	VV	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	58		
Thermal Resistance, Junction to Ambient (Note 6)	t<5s	R _θ JA	25	°C/W	
Thermal Resistance, Junction to Case (Note 6)		Rejc	10.2		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	_	-1	μA	$V_{DS} = -40V, V_{GS} = 0V$
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	-1.0	-	-2.2	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance			26	33	mΩ	$V_{GS} = -10V, I_{D} = -4.4A$
Static Dialif-Source Off-Resistance	R _{DS(ON)}	_	36	50	1112.2	$V_{GS} = -4.5V$, $I_{D} = -3.7A$
Forward Transfer Admittance	Y _{fs}	_	5.2	_	S	$V_{DS} = -15V$, $I_{D} = -4.4A$
Diode Forward Voltage	VsD	_	-0.75	-1.2	V	$V_{GS} = 0V, I_{S} = -3.9A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	1382		pF	V 201/ W 21/
Output Capacitance	Coss	_	103	_	pF	V _{DS} = -20V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	81	_	pF	1 = 1.0WH2
Gate Resistance	Rg	_	7.7	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	11.2	_	nC	
Total Gate Charge (V _{GS} = -10V)	Qg	-	23.2		nC	V _{DS} = -20V. I _D = -4.9A
Gate-Source Charge	Qgs		3.3		nC	VDS = -20V, ID = -4.9A
Gate-Drain Charge	Q_{gd}	_	3.9		nC	
Turn-On Delay Time	td(on)	_	18.4	_	ns	
Turn-On Rise Time	t _R	_	28.2	_	ns	$V_{DS} = -20V, I_{D} = -3.9A$
Turn-Off Delay Time	tD(OFF)	_	38.8	_	ns	$V_{GS} = -4.5V$, $R_{G} = 1\Omega$
Turn-Off Fall Time	tF	_	28.6	_	ns]
Reverse Recovery Time	trr	_	15.4	_	ns	1 0 0 0 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
Reverse Recovery Charge	Q _{RR}	_	5.4	_	nC	I _F = -3.9A, di/dt = 100A/μs

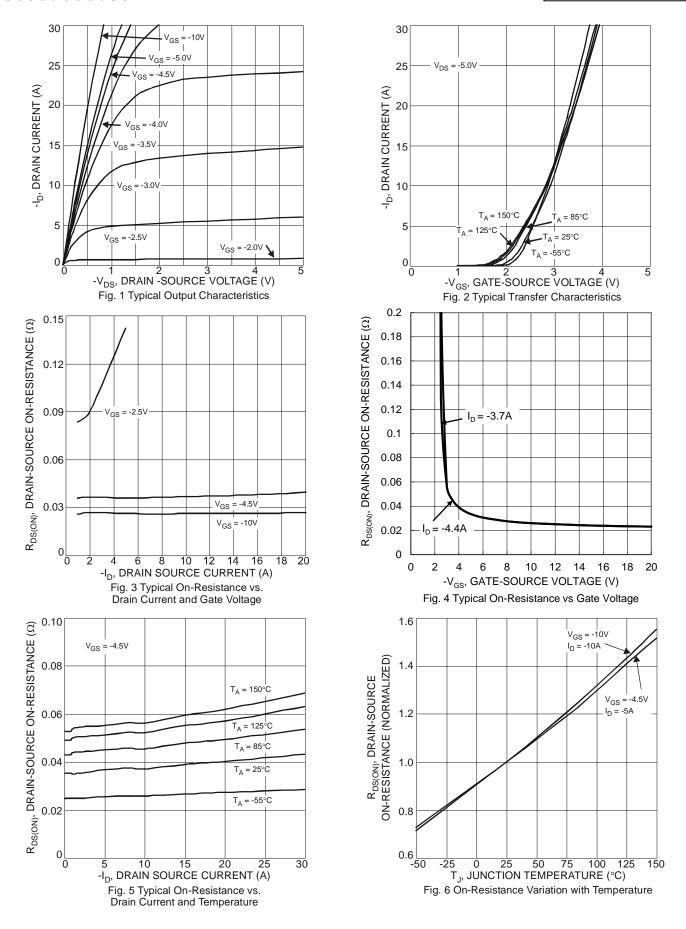
Notes:

^{5.} Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.

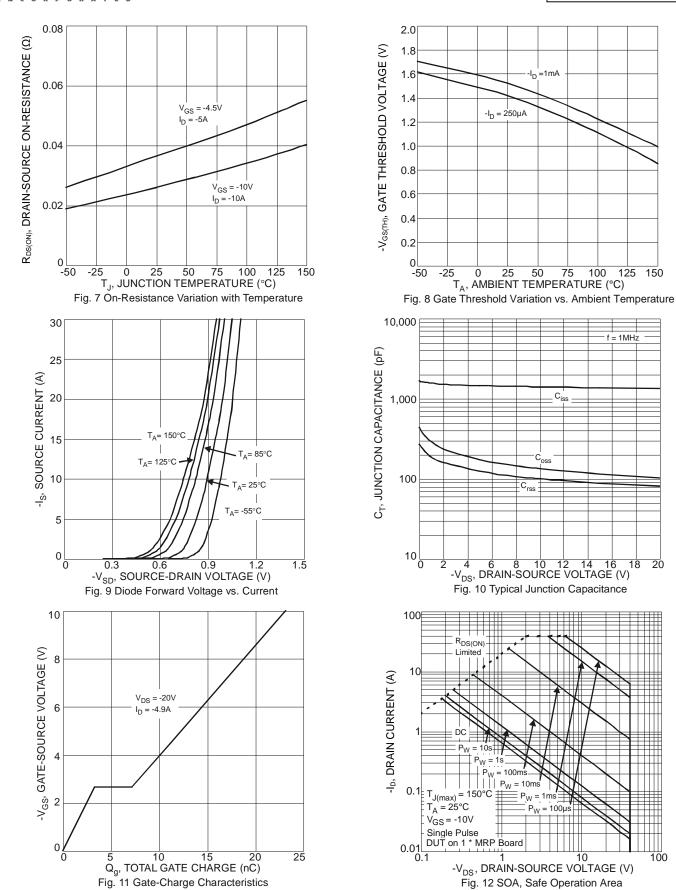
^{7.} Short duration pulse test used to minimize self-heating effect.

^{8.} Guaranteed by design. Not subject to production testing.

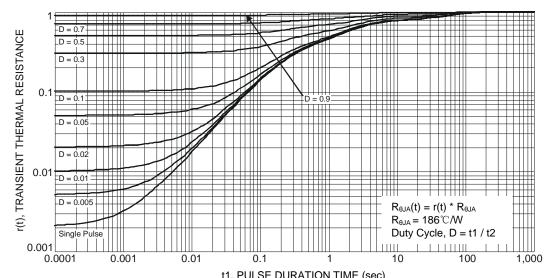












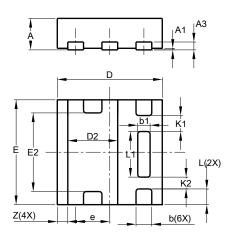
t1, PULSE DURATION TIME (sec) Fig. 13 Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type E)

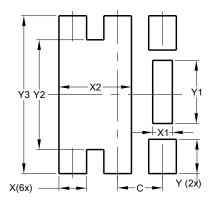


U-DFN2020-6									
	Type E								
Dim	Min								
Α	0.57	0.63	0.60						
A1	0	0.05	0.03						
A3	1	-	0.15						
b	0.25	0.35	0.30						
b1	0.185	0.285	0.235						
D	1.95	2.05	2.00						
D2	0.85	1.05	0.95						
Е	1.95	2.05	2.00						
E2	1.40	1.60	1.50						
е	_	-	0.65						
L	0.25	0.35	0.30						
L1	0.82	0.92	0.87						
K1	_	_	0.305						
K2	_	_	0.225						
Z	_	_	0.20						
All	Dimen	sions i	in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type E)



Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	0.285
X2	1.050
Υ	0.500
Y1	0.920
Y2	1.600
Y3	2.300



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